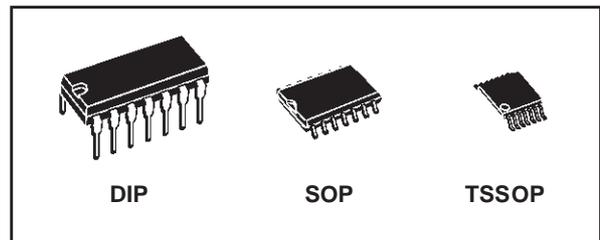




M74HCT393

DUAL BINARY COUNTER

- HIGH SPEED :
 $f_{MAX} = 80\text{MHz}$ (TYP.) at $V_{CC} = 4.5\text{V}$
- LOW POWER DISSIPATION:
 $I_{CC} = 4\mu\text{A}$ (MAX.) at $T_A = 25^\circ\text{C}$
- COMPATIBLE WITH TTL OUTPUTS :
 $V_{IH} = 2\text{V}$ (MIN.) $V_{IL} = 0.8\text{V}$ (MAX)
- SYMMETRICAL OUTPUT IMPEDANCE:
 $|I_{OH}| = I_{OL} = 4\text{mA}$ (MIN)
- BALANCED PROPAGATION DELAYS:
 $t_{PLH} \cong t_{PHL}$
- PIN AND FUNCTION COMPATIBLE WITH
 74 SERIES 393



ORDER CODES

PACKAGE	TUBE	T & R
DIP	M74HCT393B1R	
SOP	M74HCT393M1R	M74HCT393RM13TR
TSSOP		M74HCT393TTR

DESCRIPTION

The M74HCT393 is an high speed CMOS DUAL BINARY COUNTER fabricated with silicon gate C²MOS technology.

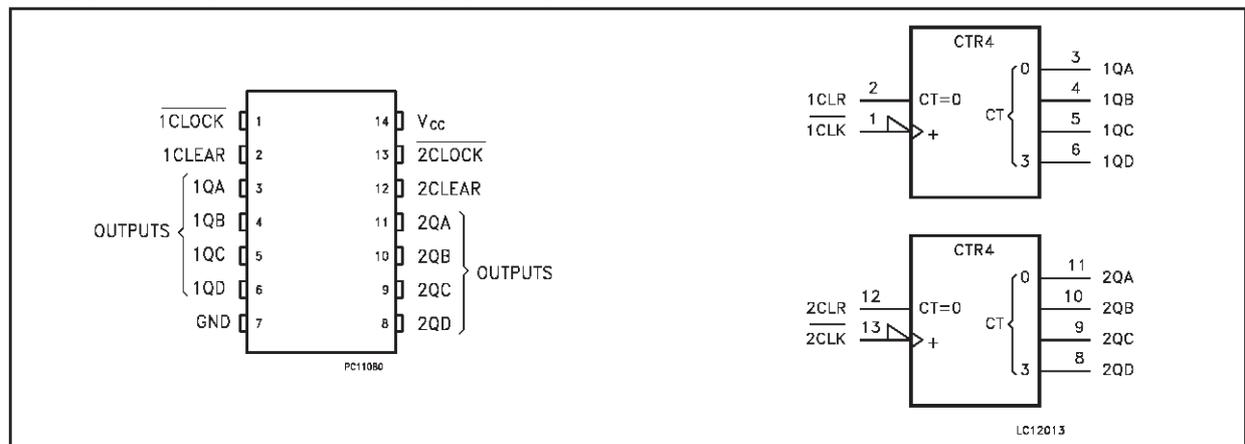
This counter circuit contains independent ripple carry counters and two 4-bit ripple carry binary counters, which can be cascaded to create a single divide by 256 counter.

Each 4-bit counter is incremented on the high to low transition (negative edge) of the clock input, and each has an independent clear input. When CLEAR(CLR) is set to high, all four bits of each

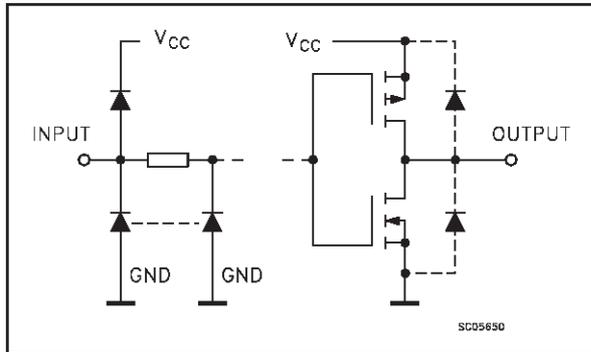
counter are set to a low level. This enables count truncation and allows the implementation of divide by N counter configurations.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 13	$\overline{1 \text{ CLOCK}}$ $\overline{2 \text{ CLOCK}}$	Clock Input Divide by 2 Section (HIGH to LOW Edge-Triggered)
2, 12	1 CLEAR 2 CLEAR	Asynchronous Master Reset Inputs
3, 4, 5, 6	1QA to 1QD	Flip Flop Outputs
11, 10, 9, 8	2QA to 2QD	Flip Flop Outputs
7	GND	Ground (0V)
14	Vcc	Positive Supply Voltage

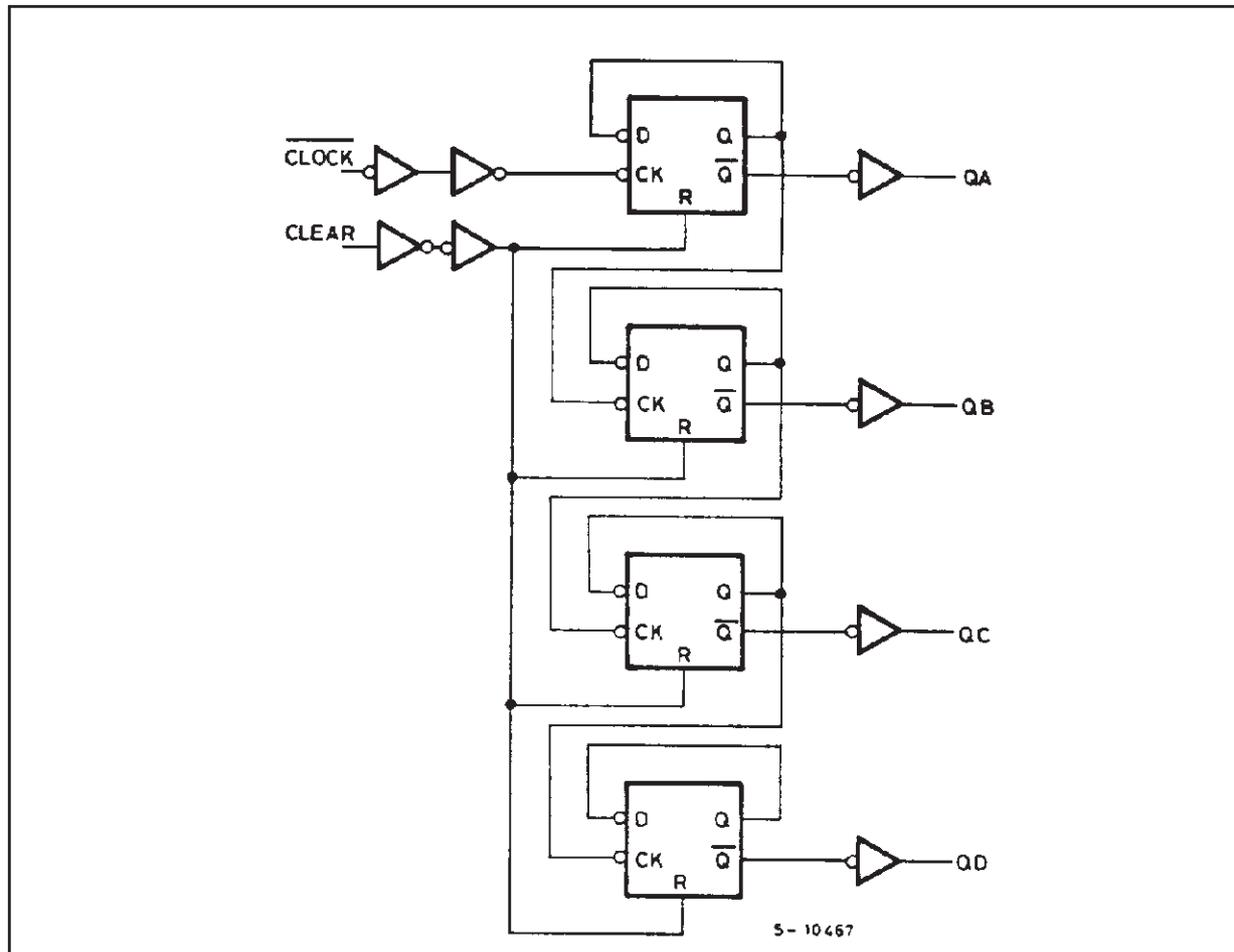
TRUTH TABLE

INPUTS		OUTPUTS			
$\overline{\text{CLOCK}}$	CLEAR	QD	QC	QB	QA
X	H	L	L	L	L
	L	COUNT UP			
	L	NO CHANGE			

X : Don't Care

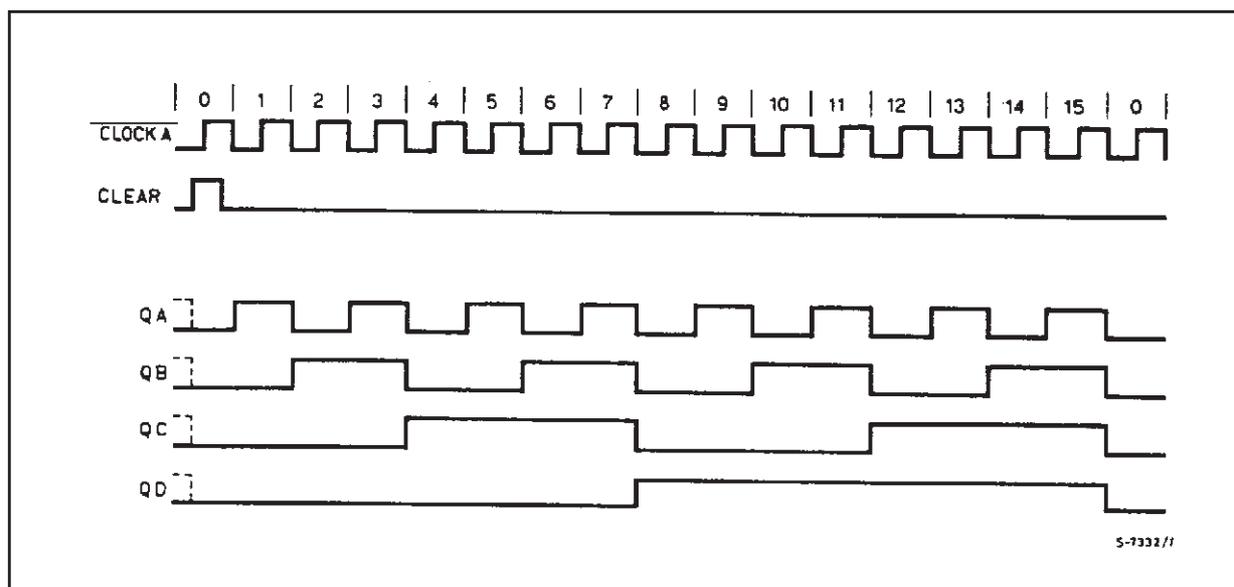
COUNT	OUTPUTS			
	QD	QC	QB	QA
0	L	L	L	L
1	L	L	L	H
2	L	L	H	L
3	L	L	H	H
4	L	H	L	L
5	L	H	L	H
6	L	H	H	L
7	L	H	H	H
8	H	L	L	L
9	H	L	L	H
10	H	L	H	L
11	H	L	H	H
12	H	H	L	L
13	H	H	L	H
14	H	H	H	L
15	H	H	H	H

LOGIC DIAGRAM



This logic diagram has not be used to estimate propagation delays

TIMING CHART



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7	V
V_I	DC Input Voltage	-0.5 to $V_{CC} + 0.5$	V
V_O	DC Output Voltage	-0.5 to $V_{CC} + 0.5$	V
I_{IK}	DC Input Diode Current	± 20	mA
I_{OK}	DC Output Diode Current	± 20	mA
I_O	DC Output Current	± 25	mA
I_{CC} or I_{GND}	DC V_{CC} or Ground Current	± 50	mA
P_D	Power Dissipation	500(*)	mW
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied

(*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	4.5 to 5.5	V
V_I	Input Voltage	0 to V_{CC}	V
V_O	Output Voltage	0 to V_{CC}	V
T_{op}	Operating Temperature	-55 to 125	°C
t_r, t_f	Input Rise and Fall Time ($V_{CC} = 4.5$ to $5.5V$)	0 to 500	ns

DC SPECIFICATIONS

Symbol	Parameter	Test Condition		Value						Unit	
		V_{CC} (V)		$T_A = 25^\circ\text{C}$			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
V_{IH}	High Level Input Voltage	4.5 to 5.5		2.0			2.0		2.0		V
V_{IL}	Low Level Input Voltage	4.5 to 5.5				0.8		0.8		0.8	V
V_{OH}	High Level Output Voltage	4.5	$I_O = -20 \mu\text{A}$	4.4	4.5		4.4		4.4		V
			$I_O = -4.0 \text{ mA}$	4.18	4.31		4.13		4.10		
V_{OL}	Low Level Output Voltage	4.5	$I_O = 20 \mu\text{A}$		0.0	0.1		0.1		0.1	V
			$I_O = 4.0 \text{ mA}$		0.17	0.26		0.33		0.40	
I_I	Input Leakage Current	5.5	$V_I = V_{CC}$ or GND			± 0.1		± 1		± 1	μA
I_{CC}	Quiescent Supply Current	5.5	$V_I = V_{CC}$ or GND			4		40		80	μA
ΔI_{CC}	Additional Worst Case Supply Current	5.5	Per Input pin $V_I = 0.5V$ or $V_I = 2.4V$ Other Inputs at V_{CC} or GND			2.0		2.9		3.0	mA

AC ELECTRICAL CHARACTERISTICS ($C_L = 50$ pF, Input $t_r = t_f = 6$ ns)

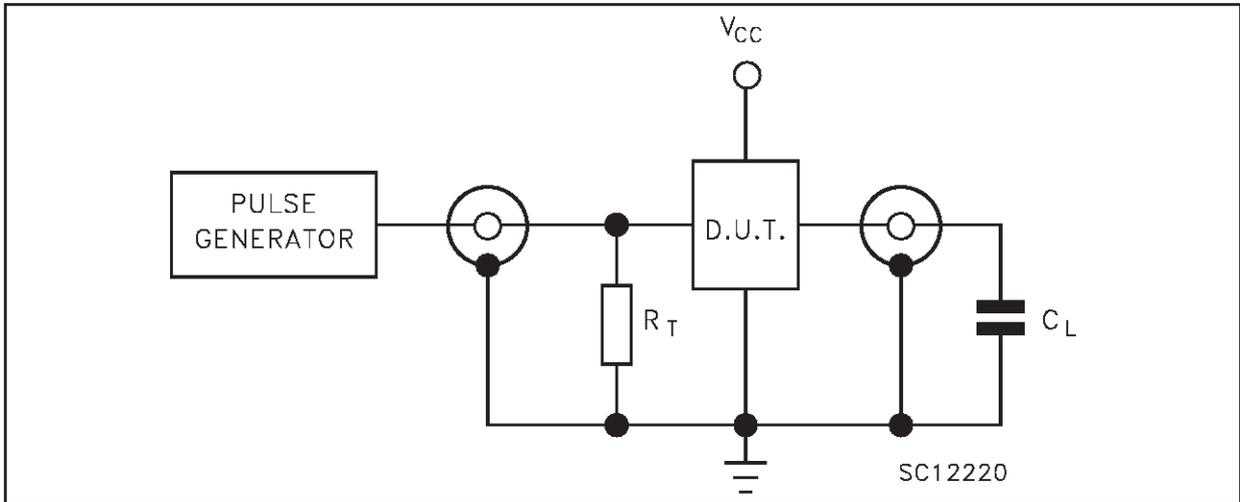
Symbol	Parameter	Test Condition		Value						Unit	
		V_{CC} (V)		$T_A = 25^\circ\text{C}$			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
t_{TLH} t_{THL}	Output Transition Time	4.5			8	15		19		22	ns
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK - QA)	4.5			19	30		38		45	ns
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK - QB)	4.5			24	37		46		56	ns
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK - QC)	4.5			28	43		54		65	ns
t_{PLH} t_{PHL}	Propagation Delay Time (CLOCK - QD)	4.5			33	51		64		77	ns
t_{PHL}	Propagation Delay Time (CLEAR - Qn)	4.5			20	31		39		47	ns
f_{MAX}	Maximum Clock Frequency	4.5		4.2	80		34				MHz
$t_{W(H)}$ $t_{W(L)}$	Minimum Pulse Width (CLOCK)	4.5			8	15		19		22	ns
$t_{W(H)}$	Minimum Pulse Width (CLEAR)	4.5			8	15		19		22	ns
t_{REM}	Minimum Removal Time	4.5				5		6		8	ns

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition		Value						Unit	
		V_{CC} (V)		$T_A = 25^\circ\text{C}$			-40 to 85°C		-55 to 125°C		
				Min.	Typ.	Max.	Min.	Max.	Min.		Max.
C_{IN}	Input Capacitance				5	10		10		10	pF
C_{PD}	Power Dissipation Capacitance (note 1)				66						pF

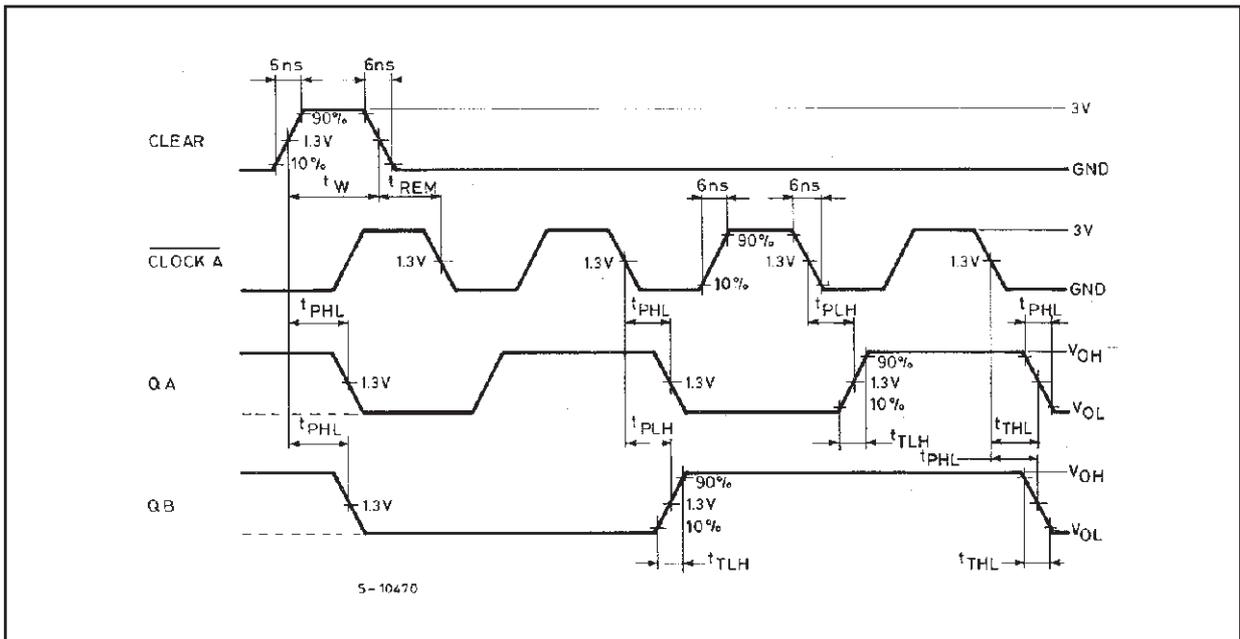
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation: $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4$ (per FLIP FLOP)

TEST CIRCUIT



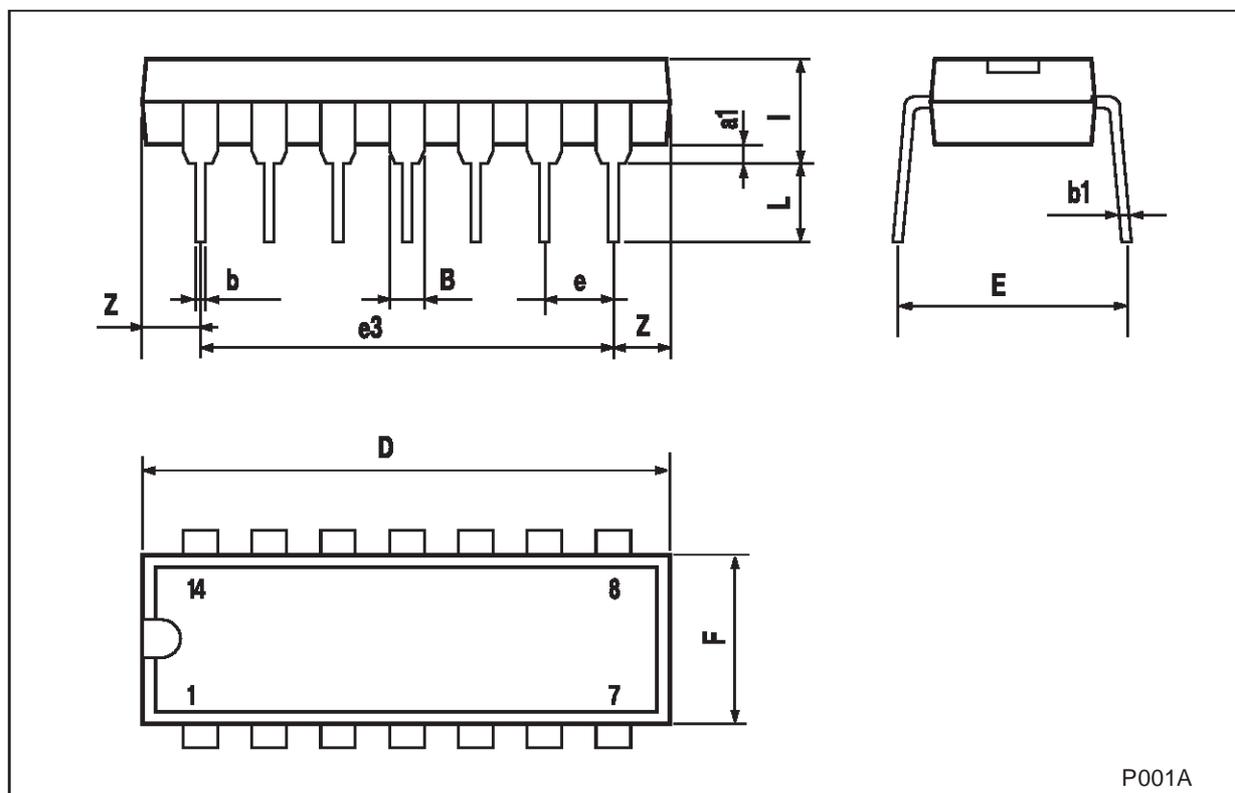
$C_L = 50\text{pF}$ or equivalent (includes jig and probe capacitance)
 $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

WAVEFORM : MINIMUM REMOVAL AND PROPAGATION DELAY TIMES, MINIMUM PULSE WIDTH
 ($f=1\text{MHz}$; 50% duty cycle)



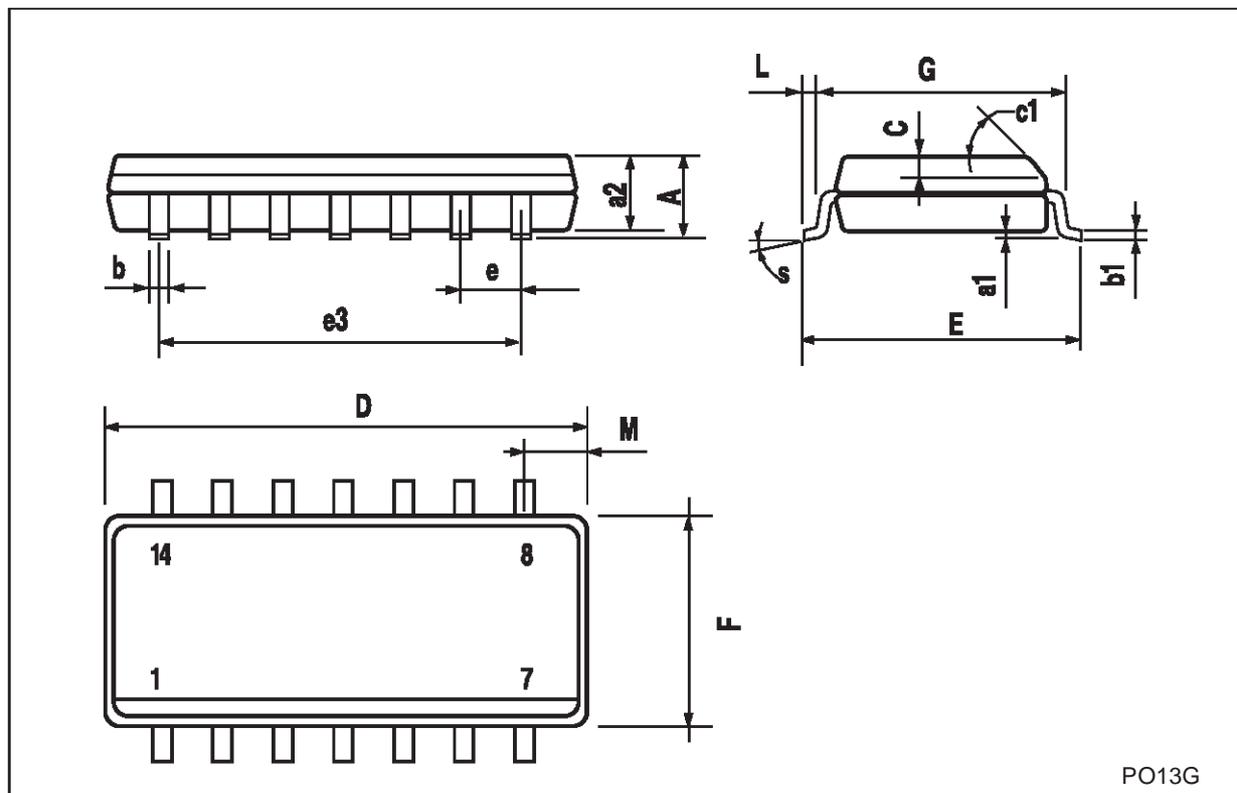
Plastic DIP-14 MECHANICAL DATA						
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DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100



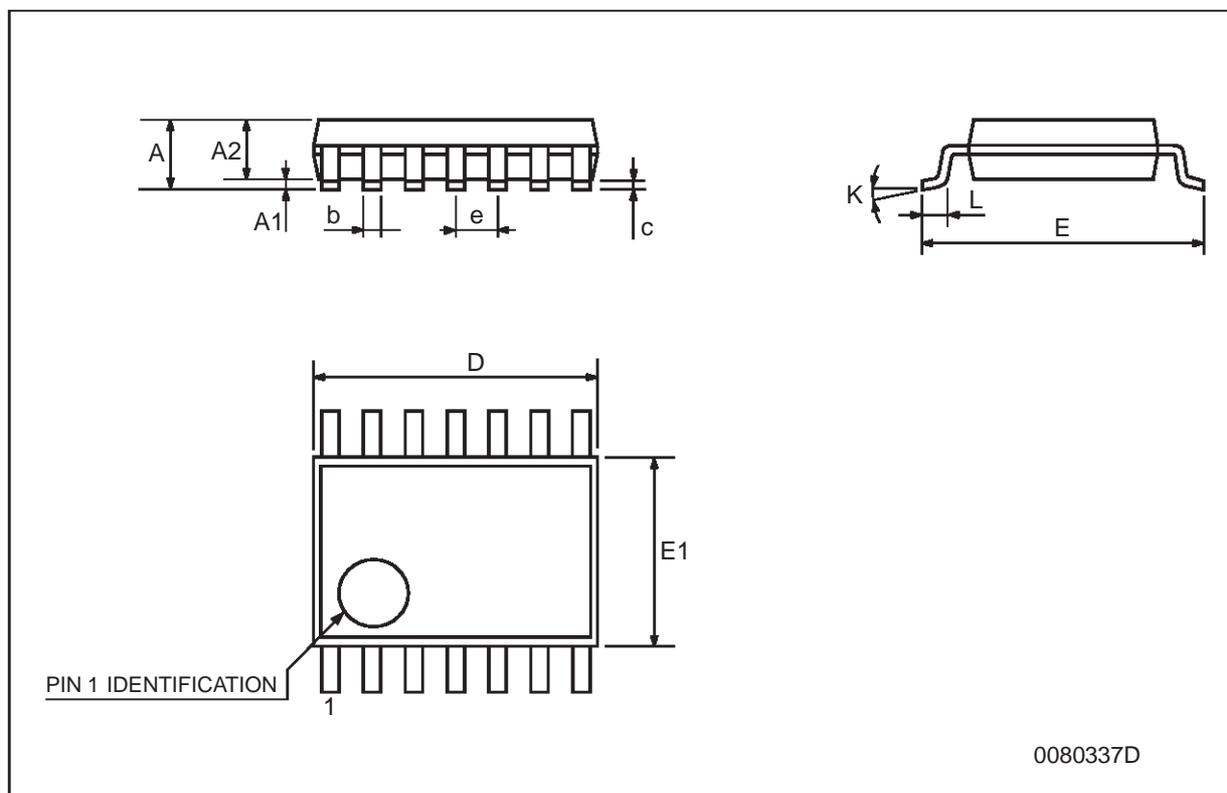
SO-14 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					



TSSOP14 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



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